Diode Semiconductor Device - Page 1 of 1



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Inclosure	e Material:
Glass and	d metal
Overall L	-ength:
0.200 inc	hes
Terminal	Length:
1.000 inc	hes
Overall D	Diameter:
0.240 inc	hes
Mounting	g Method:
Terminal	
Features	Provided:
Hermetic	ally sealed case
Semicon	ductor Material:
Silicon	
Voltage I	Rating In Volts Per Characteristic:
400.0 rev	verse voltage, instantaneous and 280.0 reverse voltage, total rms
Current I	Rating Per Characteristic:
750.00 m	illiamperes source cutoff current
Maximur	n Operating Tempurature Per Measurement Point:
150.0 deg	grees celsius ambient air
Special F	Features:
Insulation	n sleeve included
Terminal	Type And Quantity:
2 uninsul	ated wire lead
Shelf Life	e:
N/a	
Unit Of M	leasure:
Demilitar	rization:
No	
Fiig:	
A110a0	